

# Complementary Silicon Power Transistors

... designed for general-purpose switching and amplifier applications.

- DC Current Gain —  $h_{FE} = 20-70$  @  $I_C = 4.0$  Adc
- Collector-Emitter Saturation Voltage —  $V_{CE(sat)} = 1.1$  Vdc (Max) @  $I_C = 4.0$  Adc
- Excellent Safe Operating Area

## MAXIMUM RATINGS

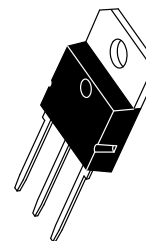
Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	60	Vdc
Collector-Emitter Voltage	$V_{CER}$	70	Vdc
Collector-Base Voltage	$V_{CB}$	100	Vdc
Emitter-Base Voltage	$V_{EB}$	7.0	Vdc
Collector Current — Continuous	$I_C$	1.5	Adc
Base Current	$I_B$	7.0	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	90 0.72	Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-65 to +150	$^\circ\text{C}$

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.39	$^\circ\text{C/W}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	35.7	$^\circ\text{C/W}$

**NPN**  
**TIP3055**  
**PNP**  
**TIP2955**

**15 AMPERE**  
**POWER TRANSISTORS**  
**COMPLEMENTARY**  
**SILICON**  
**60 VOLTS**  
**90 WATTS**



CASE 340D-02

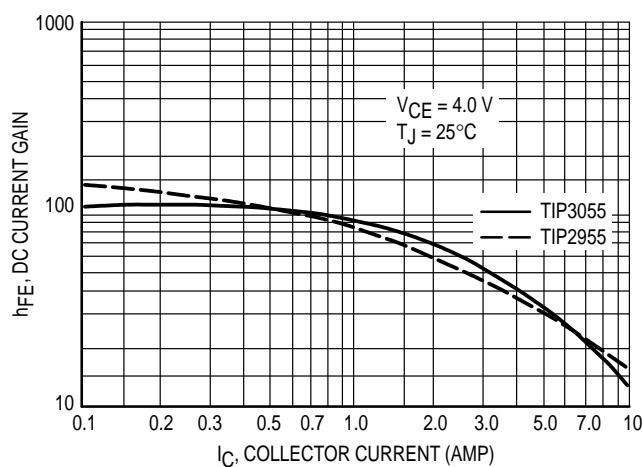


Figure 1. DC Current Gain



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### ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Collector–Emitter Sustaining Voltage (1) ( $I_C = 30\text{ mAdc}$ , $I_B = 0$ )	$V_{CEO(sus)}$	60	—	Vdc
Collector Cutoff Current ( $V_{CE} = 70\text{ Vdc}$ , $R_{BE} = 100\text{ Ohms}$ )	$I_{CER}$	—	1.0	mAdc
Collector Cutoff Current ( $V_{CE} = 30\text{ Vdc}$ , $I_B = 0$ )	$I_{CEO}$	—	0.7	mAdc
Collector Cutoff Current ( $V_{CE} = 100\text{ Vdc}$ , $V_{BE(off)} = 1.5\text{ Vdc}$ )	$I_{CEV}$	—	5.0	mAdc
Emitter Cutoff Current ( $V_{BE} = 7.0\text{ Vdc}$ , $I_C = 0$ )	$I_{EBO}$	—	5.0	mAdc

### ON CHARACTERISTICS (1)

DC Current Gain ( $I_C = 4.0\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ ) ( $I_C = 10\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ )	$h_{FE}$	20 5.0	70 —	—
Collector–Emitter Saturation Voltage ( $I_C = 4.0\text{ Adc}$ , $I_B = 400\text{ mAdc}$ ) ( $I_C = 10\text{ Adc}$ , $I_B = 3.3\text{ Adc}$ )	$V_{CE(sat)}$	— —	1.1 3.0	Vdc
Base–Emitter On Voltage ( $I_C = 4.0\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ )	$V_{BE(on)}$	—	1.8	Vdc

### SECOND BREAKDOWN

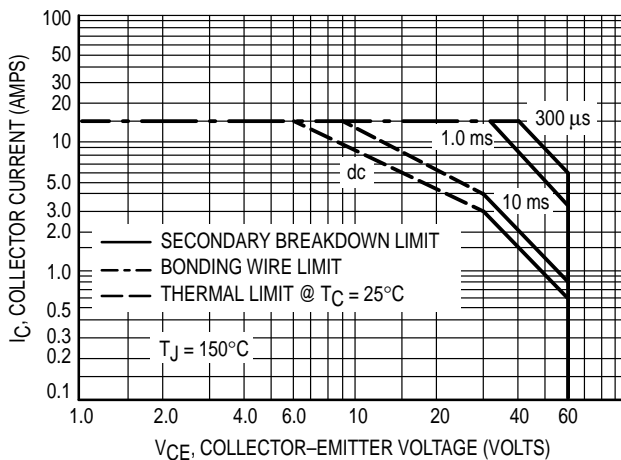
Second Breakdown Collector Current with Base Forward Biased ( $V_{CE} = 30\text{ Vdc}$ , $t = 1.0\text{ s}$ ; Nonrepetitive)	$I_{s/b}$	3.0	—	Adc
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### DYNAMIC CHARACTERISTICS

Current Gain — Bandwidth Product ( $I_C = 0.5\text{ Adc}$ , $V_{CE} = 10\text{ Vdc}$ , $f = 1.0\text{ MHz}$ )	$f_T$	2.5	—	MHz
Small–Signal Current Gain ( $V_{CE} = 4.0\text{ Vdc}$ , $I_C = 1.0\text{ Adc}$ , $f = 1.0\text{ kHz}$ )	$h_{fe}$	15	—	kHz

(1) Pulse Test: Pulse Width =  $300\text{ }\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

NOTE: For additional design curves, refer to electrical characteristics curves of 2N3055.

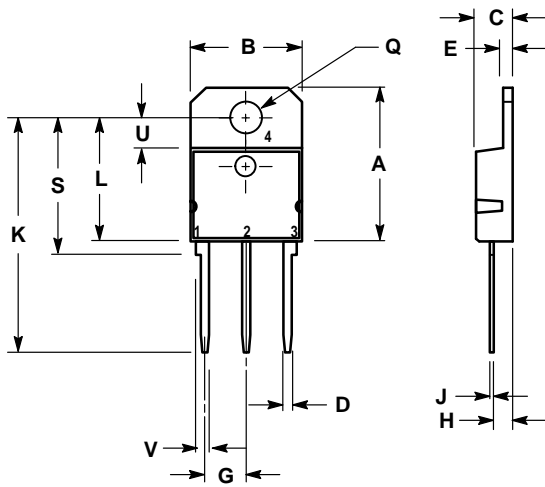


**Figure 2. Maximum Rated Forward Bias Safe Operating Area**

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 2 is based on  $T_C = 25^\circ\text{C}$ ;  $T_{J(pk)}$  is variable depending on power level. Second breakdown pulse limits are valid for duty cycles to 10% but must be derated for temperature.

PACKAGE DIMENSIONS

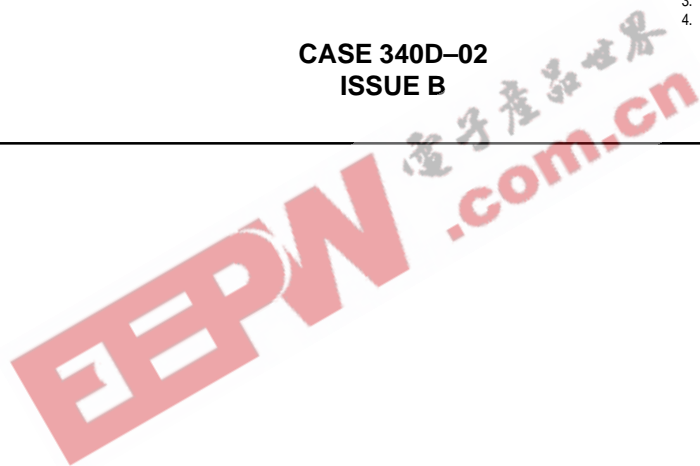


NOTES:  
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.  
 2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	—	20.35	—	0.801
B	14.70	15.20	0.579	0.598
C	4.70	4.90	0.185	0.193
D	1.10	1.30	0.043	0.051
E	1.17	1.37	0.046	0.054
G	5.40	5.55	0.213	0.219
H	2.00	3.00	0.079	0.118
J	0.50	0.78	0.020	0.031
K	31.00 REF		1.220 REF	
L	—	16.20	—	0.638
Q	4.00	4.10	0.158	0.161
S	17.80	18.20	0.701	0.717
U	4.00 REF		0.157 REF	
V	1.75 REF		0.069	


STYLE 1:  
 PIN 1. BASE  
 2. COLLECTOR  
 3. EMITTER  
 4. COLLECTOR

CASE 340D-02  
 ISSUE B



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### How to reach us:

**USA/EUROPE/Locations Not Listed:** Motorola Literature Distribution;  
P.O. Box 20912; Phoenix, Arizona 85036. 1-800-441-2447 or 602-303-5454

**MFAX:** RMFAX0@email.sps.mot.com – TOUCHTONE 602-244-6609  
**INTERNET:** <http://Design-NET.com>

**JAPAN:** Nippon Motorola Ltd.; Tatsumi-SPD-JLDC, 6F Seibu-Butsuryu-Center,  
3-14-2 Tatsumi Koto-Ku, Tokyo 135, Japan. 03-81-3521-8315

**ASIA/PACIFIC:** Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park,  
51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852-26629298



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